

Optical and Electrical Modeling of Dye Sensitized Solar Cell: Influence of the Overlap Distance Between TiO_2 Particles

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Abstract: Dye sensitized solar cells (DSSC) are used for photovoltaic applications. The paper presents a methodology for optical and electrical modeling of dye-sensitized solar cells (DSSCs). In order to take into account the influence of the overlap distance between two TiO_2 particles on the cell an optoelectronic model for DSSC is presented in this paper. From the radiative transfer equation and Mie theory, the optical generation rate of cell is deduced. Coupling the output of the optical model (the dye absorption rate) to an electrical model allows determination of short-circuit current density and maximum power output. Due to our model, the dependence effects of the overlap distance upon the porosity, the optical generation rate, the short circuit current density and the maximum power output are evidenced. Thus, we see that when the overlap distance increases the porosity decreases. In addition, when the overlap distance increases, the absorption rate decreases when the overlap distance is greater than TiO_2 radius divide by 5. Moreover, we see that when the overlap distance is lower than the TiO_2 radius divided by 5, the short circuit current density and the maximum power output increase. However, when the overlap distance is higher than TiO_2 radius divided by 5 they decrease. Thus, according to the model, we see that the optimal overlap distance is equal to TiO_2 radius divide by 5. Our results agree with those found in the literature.

Keywords: Dye-Sensitized Solar Cell, Optical Parameters, Electrical Parameters, Overlap Distance, TiO_2 Radius

1. Introduction

Dye sensitized solar cells (DSCs) as alternative to solar cells have been widely studied in recent years [1-3]. Record efficiencies of over 11% have been achieved with ruthenium-complex sensitizers on laboratory-scale devices. [4-6] Dye sensitized solar cell is a mixture of nanostructured films, a sensitizer and an electrolyte containing the mediator sandwiched between two electrodes: a conductive oxide as an anode and a counter electrode as cathode as depicted in figure 1. The efficiency of absorption of the incoming light by the dye is one of the paramount parameters for the cell performance. Accordingly, the peculiar composition of the

photoactive layer makes the dye-sensitized solar cells very complicated to establish an optoelectronic model. Indeed, it is composed of a mixture of three materials (titanium dioxide, dye molecules and tri-iodide ions immersed within the electrolyte) which could raise homogeneity problems.

Various optical [7-8], electrical [9-18] and optoelectronic model [19-20] have been developed.

The purpose of our study is to present an optoelectronic model that take into account the influence of overlap distance on dye sensitive solar cell.

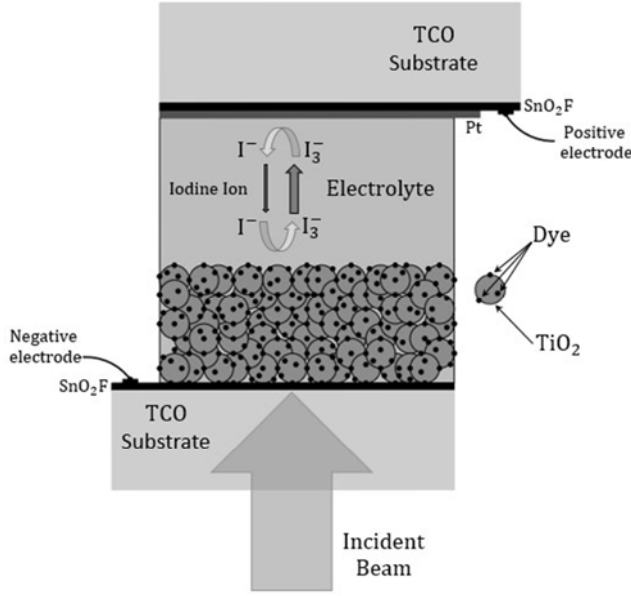


Figure 1. Structure of the Dye sensitized solar cell.

2. Computational Model

2.1. Optical Model

The model considered is depicted in figure 2. Where x represents the depth of the photoactive layer. Thus, our study is essentially limited to the photoactive layer sandwiched between the two electrodes. The photoactive layer is a mixture of Titanium dioxide (TiO_2), a dye (Z907), a mediator and an electrolyte $\text{I}^- / \text{I}_3^-$.

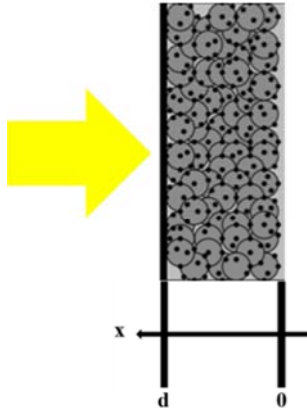


Figure 2. Schematic of the photoactive layer.

First, we calculate the scattering cross sections and absorption through the Mie theory in the case of a mono-dispersed particle size. Our medium is composed of three compounds; we calculate the scattering cross sections for the nanostructured film (TiO_2 here) and the electrolyte / mediator. Indeed, the particle size of dyes is low [7], they do not participate in the scattering process. Then macroscopic scattering and absorption coefficient s and k will be calculated for each compound.

$$s_i = n_{sca,i} \sigma_{sca,i} \quad (1)$$

$$k_j = n_{abs,j} \sigma_{abs,j} \quad (2)$$

Where i = electrolyte/mediator or TiO_2 ; j = dye or electrolyte /mediator. The particle density of the electrolytic/mediator will be given by the equation:

$$N_{electrolyte/mediator} = N_{\text{TiO}_2} \times \frac{P}{1-P} \quad (3)$$

With P the porosity.

The hypothesis we making here is to consider the TiO_2 /Dye as one particle. Since the diffusion of the dyes particles is very low we consider that the particle (TiO_2 /Dye) have the same dimensions as the simple TiO_2 particle [7]. On the other hands since the TiO_2 particle doesn't absorb we consider also that the absorption of the particle (TiO_2 /Dye) is just coming from the simple dye particle Therefore we have:

$$N_{dye} = N_{\text{TiO}_2} \quad (4)$$

Then:

$$K = k_{dye} + k_{electrolyte/mediator} \quad (5)$$

$$S = s_{\text{TiO}_2} + s_{electrolyte/mediator} \quad (6)$$

To determine the porosity, we define the system as follows: First, the radiuses of all the nanoparticles are the same. Colloids are considered perfectly spherical. The penetration length for two neighboring particles is given by:

$$d_p = 2r(1-h) \quad (7)$$

Where d_p : distance between nanoparticles, r : radius of the sphere, h : the overlap distance

Equation (7) can be visualized in figure 3.

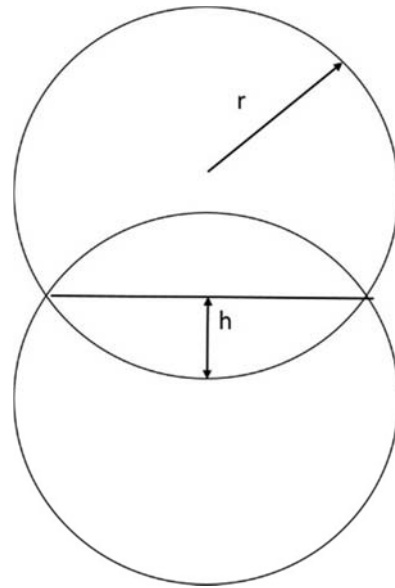


Figure 3. Schematic picture of the overlap between two particles.

Taylor et al's equations are used to determine the porosity [21-22]. In these equations, the porosity is deduced by determining the volume of a single cell and the solid volume (sphere in our case) in a single cell.

The volume of the single cell is a function of the packing factor and diameter of the sphere. The volume is:

$$V = \alpha_m d^3 \quad (8)$$

α_m : packing factor, d : diameter of the sphere.

With the volume of the single cell known, the calculation of the porosity requires the determination of the total volume of the sphere in the single cell. For this calculation, Taylor et al based themselves on the calculations of Deb [23]. It determines the volume of a sphere taking into account the overlapping surface between the spheres. Thus, the volume of the sphere in the single cell is:

$$V_b = \frac{\pi}{6}(d+2h)^3 - CN \frac{\pi}{3} h^3 \left[3\left(\frac{d}{2} + h\right) - h \right] \quad (9)$$

h : overlap distance; CN : coordination number

The first term on the right corresponds to the total volume of the sphere. The second term corresponds to the sum of the volumes of each spherical cape. Taylor et al. [21-22] used equations for the volume of single cell (6), the volume of sphere (7), and then obtained the following equation for the calculation of the porosity of a cell containing a number n of spheres

$$P = 1 - \frac{n\pi}{\alpha_m} \left[\frac{2 - CN \left(\frac{2h}{d}\right)^3}{12} + \frac{4 - CN \left(\frac{2h}{d}\right)^2}{8} \frac{1}{2} \left(\frac{2h}{d}\right) + \frac{1}{6} \right] \quad (10)$$

We will calculate the porosity for a diamond-like structure using equation (8) and Table 1.

Table 1. Characteristic of diamond like structure.

Structure	Coordination number	Number of spheres by unit cell	Packing factor α_m
Diamond	4	8	12.35

Afterwards the macroscopic coefficients K and S are used to calculate the collimated flux (I_c and J_c) and diffused flux (I_d and J_d). Basically, the 4-flux approximation of the radiative transfer equation [24] given by equations. (7, 8, 9, 10) was considered. These different fluxes are illustrated in figure 3. In fact, the variation of the flows in the medium with an infinitesimal value of the thickness dx can be established using the equilibrium between the scattering and the absorption energy in forward and backward.

$$\frac{dI_c(x)}{dx} = (K + S)I_c(x) \quad (11)$$

$$\frac{dI_c(x)}{dx} = (K + S)I_c(x) \quad (12)$$

$$\begin{aligned} \frac{dI_d(x)}{dx} &= \gamma K I_d(x) + \gamma(1 - \zeta) S I_d(x) \\ &\quad - \gamma(1 - \zeta) S J_d(x) \\ &\quad - \zeta S I_c(x) - (1 - \zeta) S J_c(x) \end{aligned} \quad (13)$$

$$\begin{aligned} \frac{dJ_d(x)}{dx} &= -\gamma K J_d(x) - \gamma(1 - \zeta) S J_d(x) \\ &\quad + \gamma(1 - \zeta) S I_d(x) \\ &\quad + (1 - \zeta) S I_c(x) + \zeta S J_c(x) \end{aligned} \quad (14)$$

The factor γ is the equivalent path length for the diffuse fluxes, which ranges from 1 for collimated light to 2 for isotropic scattered light [25]. Thus, the analytical expression of the forward scattering ratio (ζ) is obtained from C. Rozé et al. analysis [26].

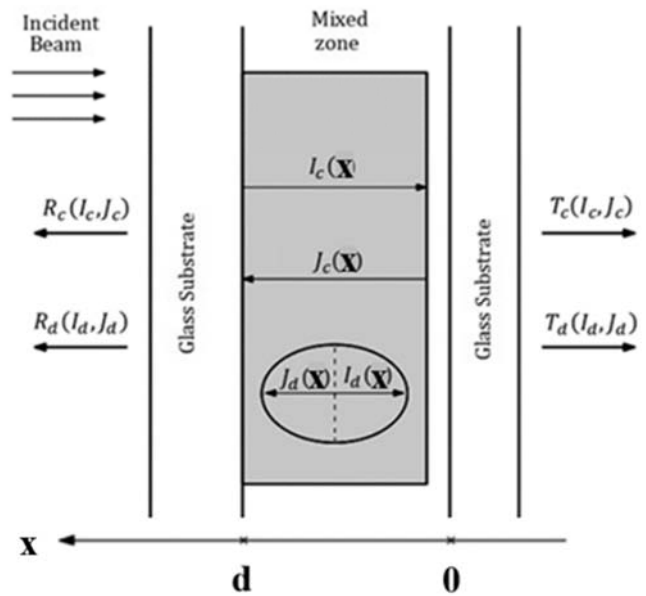


Figure 4. Schema of the cell with different flux.

The four flux I_c , I_d , J_c and J_d included in the previous equations, (7), (8), (9) and (10) are determined by taking into account the following boundary conditions.

At the Glass/Mixed zone: $x=a$

$$I_c(a) = (1 - r_c) I_c^a + r_c J_c(a) \quad (15)$$

$$I_d(a) = (1 - r_d) I_d^a + r_d J_d(a) \quad (16)$$

I_c^a and I_d^a are the incident collimated flux and the incident diffuse flux at the interface $x=a$. I_c^a can be determined by taking into account the interference effects at the glass/mixed zone and air/glass interfaces and is given as:

$$I_c^a = \frac{(1 - r_c^b)}{1 - (r_c^b r_c)} I_0 \quad (17)$$

In fact, I_d^a is equal to zero and I_0 is the incoming light.

At the Mixed zone/Glass: $x=0$

By considering the reflection effects at the air/glass and the glass/mixed interfaces the following conditions can be established:

$$J_c(0) = \left[\frac{r_c(1 - 2r_c^b) + r_c^b}{1 - r_c^b r_c^b} \right] I_c(0) \quad (18)$$

$$J_d(0) = \left[\frac{r_d^b(1 - 2r_d) + r_d^i}{1 - r_d^b r_d} \right] I_d(0) \quad (19)$$

where r_c , r_d , r_c^b , r_d^b the reflective coefficient of collimated beam, the reflective coefficient of radiation diffuse beam, the reflective coefficient of collimated beam at the back, the reflective coefficient of radiation diffuse beam at back side respectively.

Where:

$$r_c = r_d = \left| \frac{\tilde{n}_{medium} - \tilde{n}_{air}}{\tilde{n}_{medium} + \tilde{n}_{air}} \right|^2 \quad (20)$$

$$r_c^b = r_d^b = \left| \frac{\tilde{n}_{electrolyte} - \tilde{n}_{air}}{\tilde{n}_{electrolyte} + \tilde{n}_{air}} \right|^2 \quad (21)$$

Where \tilde{n}_{medium} is determined using Bruggeman theory. Then, the 4-flux are:

$$I_c(x) = C_1 \exp[(K + S)x] \quad (22)$$

$$J_c(x) = C_2 \exp[-(K + S)x] \quad (23)$$

$$I_d(x) = C_3 \exp(\sqrt{A_1}x) + C_4 \exp(-\sqrt{A_1}x) + C_5 \exp[(K + S)x] + C_6 \exp[-(K + S)x] \quad (24)$$

$$I_d(x) = C_7 \exp(\sqrt{A_1}x) + C_8 \exp(-\sqrt{A_1}x) + C_9 \exp[(K + S)x] + C_{10} \exp[-(K + S)x] \quad (25)$$

Where A_1 , C_1 , C_2 , C_3 , C_4 , C_5 , C_6 , C_7 , C_8 , C_9 and C_{10} function of K and S .

Thus, the local optical absorption rate per unit volume [8] can be established using the expression below:

$$g(x) = KI_c(x) + KJ_c(x) + \gamma KI_d(x) + \gamma KJ_d(x) \quad (26)$$

Hence, the optical photons absorption rate is deduced from $g(x)$ [27], and is expressed as:

$$G_a(x) = \frac{g(x)}{\frac{hc}{\lambda}} \quad (27)$$

And G_{dye} is deduced by:

$$G_{dye}(\lambda, x) = \frac{\alpha_{dye}}{\alpha_{medium}} G_{medium}(\lambda, x) \quad (28)$$

Finally, the optical photo-generation rate of the DSC is

given by:

$$G(x) = G_{dye}(\lambda, x) \times \eta \quad (29)$$

where η being the injection rate of electrons.

2.2. Electrical Model

The charge generation function $G_e(x) = \eta_{inj} G_{dye}(x)$, is coupled to an electrical model for free charge carriers. Here, for simplicity, we do not include ionic transport in the electrolyte and the reduction of triiodide at the counter-electrode. The electrical model is based on the stationary continuity equation. We suppose that there is no trapping states, i.e the electron is only in the conduction band of the TiO₂ layer. A purely diffusive transport equation for the electrical current density J is taken [9]. Then, in the ideal model case, only electrons from the conduction band can recombine with triiodide in the electrolyte, and the recombination rate is taken to be first order in $n(x)$ ($n(x)$: carriers density). This leads to a linear differential equation for $n(x)$:

$$L^2 \frac{d^2 n(x)}{dx^2} - [n(x) - n_0] + \tau_0 G_e(x) = 0 \quad (30)$$

Here, $L = \sqrt{\tau_0 D_0}$ is the constant electron diffusion length, τ is the electron lifetime, and n_0 is the electron number density at equilibrium in the dark.

Since the porosity of the electrode influences the electron transport, the expression of the porosity of the electron diffusion coefficient D_0 can be expressed as [28]:

$$D_0 = a |P - P_c|^\mu \text{ for } P \geq 0.41 \quad (31)$$

$$D_0 = 1.69 \times 10^{-4} \begin{pmatrix} -17.48P^3 + 7.39P^2 \\ -2.89P + 2.15 \end{pmatrix} \quad (32)$$

for $P < 0.41$

Where $a = 4.10^{-4} \text{ cm}^2 \cdot \text{s}^{-1}$, $\mu = 0.82$, $P_c = 0.76$

The electron number density in the dark n_0 is given by:

$$n_0 = N_c e^{\frac{(E_{F0} - E_c)}{k_B T}} \quad (33)$$

where N_c is the effective density of the conduction band states, E_c is the conduction band energy, and E_{F0} is the Fermi level in the dark, which is equilibrated with the redox potential of the iodide/triiodide couple.

The boundary conditions to equation (31) are

$$n(x = d) = n_0 e^{\frac{qV}{k_B T}} \quad (34)$$

And

$$\left. \frac{dn}{dx} \right|_{x=0} = 0 \quad (35)$$

where V is the photo-voltage.

$$J_{sc} = -eD_0 \left. \frac{dn}{dx} \right|_{x=d} \quad \text{for } V=0 \quad (36)$$

3. Results and Discussion

After calculating the analytical expressions presented in the previous section, a numerical code implemented with Matlab is established. The numerical results are presented in this section. Thus, the macroscopic parameters such as the generation rate, the photocurrent density and the maximum

power output of a DSSC based on several parameters are studied: wavelengths of the incident light overlap distance between two TiO_2 particles, the depth of the cell.

The analytical methods were validated by data found in the literature.

In figure 5, we plot the generation rate depending on the photoactive layer. We make a comparison between the values obtained by our model and the Beer-Lambert law. However, the optical method based on Mie theory and RTE provides a more detailed view as shown in the following paragraphs.

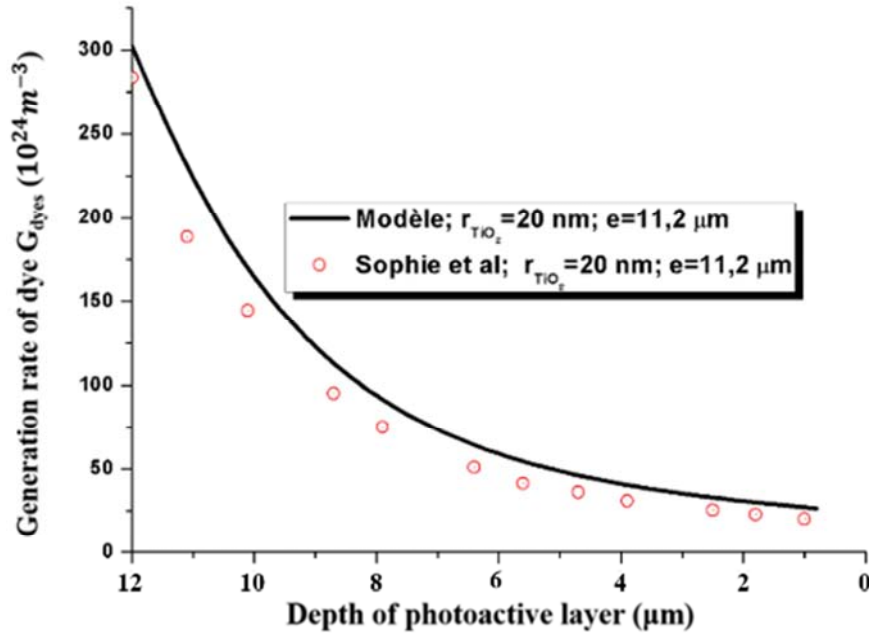


Figure 5. Generation rate of photoactive layer as a function of the cell: Generation rate of photoactive layer as a function of the cell.

The modeling of the short-circuit photocurrent density is compared with the experimental results of Saito et al (figure 6) [29]. The model and the experimental results show a good agreement.

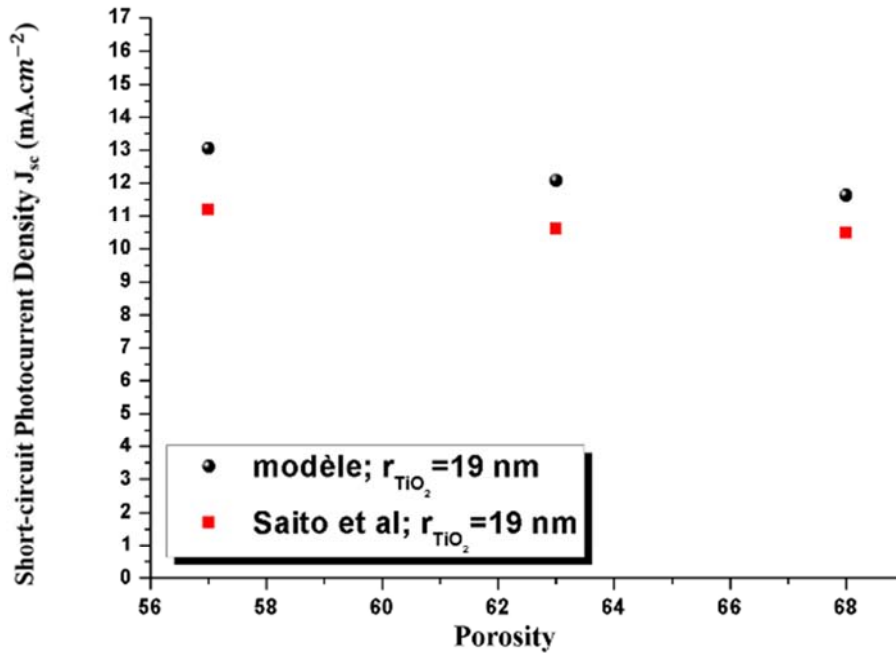


Figure 6. Short circuit photocurrent density as a function of porosity.

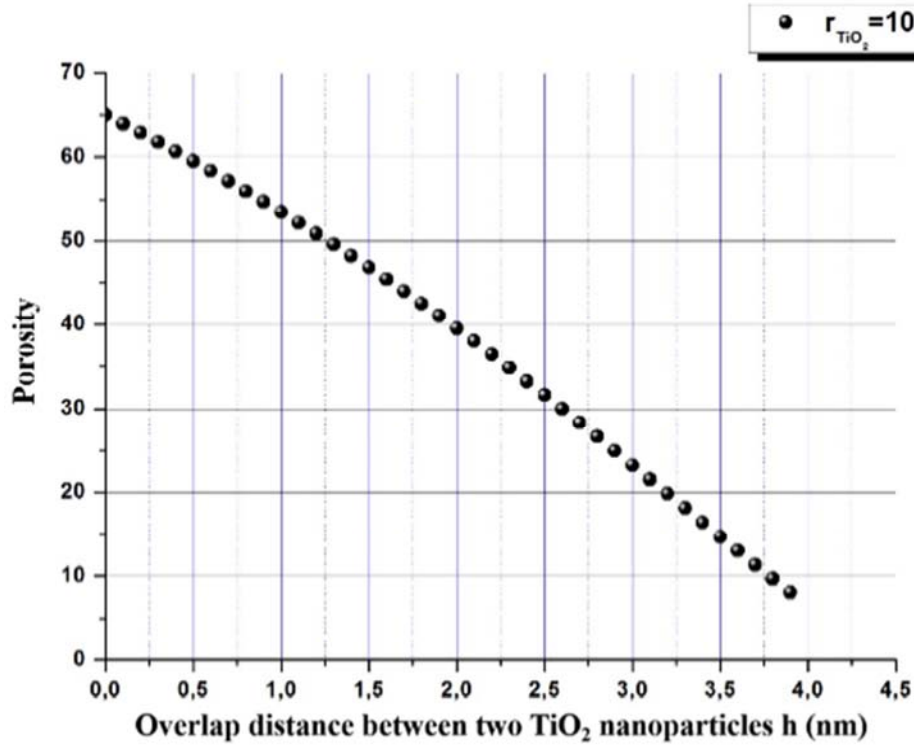


Figure 7. Porosity depending on the overlap distance h .

Figure 7 shows the variation of porosity as a function of the overlap distance between two TiO_2 particles h for a radius equal to 10 nm. We see that, when h increases, the porosity decreases. In fact, when h increases the package density increases, which lead to a reduction of the porosity.

Figure 8 represents the profile of the density of dyes as a function of TiO_2 radius for different values of overlap distance between two TiO_2 nanoparticles. We see that when the radius increases the density of dye decreases. In fact, when the radius increases the specific surface area is reduced. Moreover, we see that when the overlap distance is smaller than 2 nm (figure 8.a) the density of dyes is nearly the same.

However, when the overlap distance is greater than 2 nm (figure 8.b) the density of dyes decreases. When the overlap distance is smaller than 2 nm, the specific surface area is proportional to the overlap distance. Thus, the increase of overlap distance causes a small reduction of the specific surface area. Then, the variation of the density of dyes is small. However, when the overlap distance is greater than 2 nm, the specific surface area is proportional to the square of the porosity. The reduction of the porosity causes a reduction of the specific surface area. Then, the reduction of surface area causes the decrease of density of dyes.

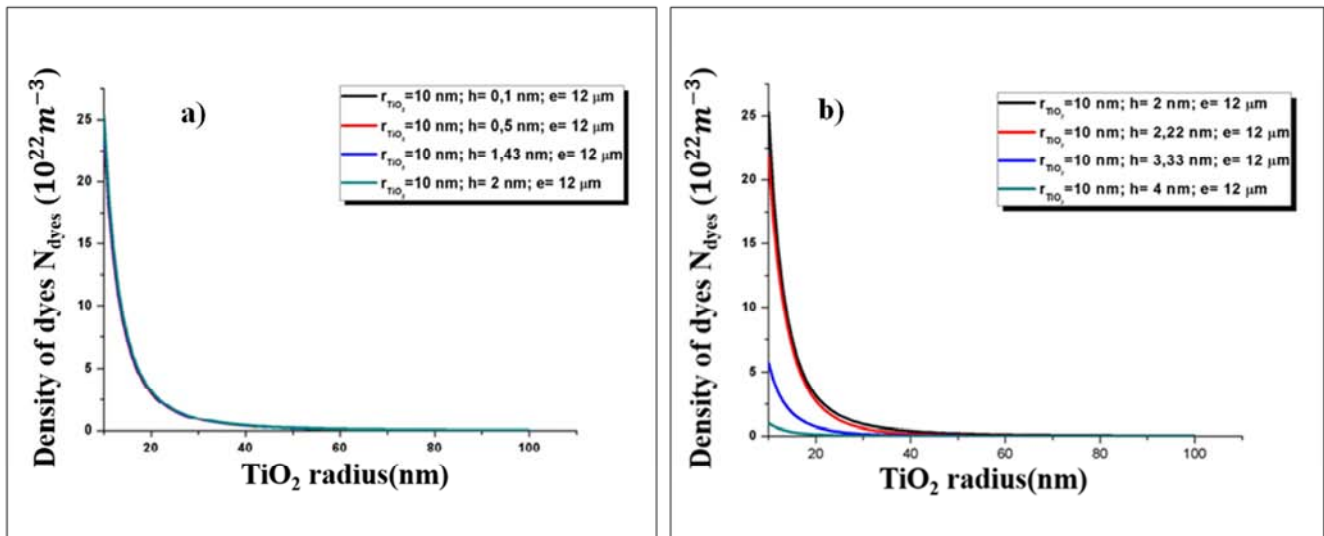


Figure 8. Density of dye as a function of overlap distance between two TiO_2 particles.

Figure 9 represents the generation rate as a function of the depth of the photoactive layer for different values of the overlap distance. We notice that the absorption of photons is greater at the interface anode/ photoactive layer. Indeed, the incident flux is reduced when the light passes through the photoactive layer. Moreover, as for figure 8, when the overlap distance is smaller than 2 nm (figure 8. a), we have a small reduction of the generation rate when the overlap distance increases. However, when the overlap distance is

greater than 2 nm (figure 8. b), when the overlap distance increases the generation rate decreases. Indeed, as shown in figure 4, when the overlap distance is smaller than 2 nm, a growth of the overlap distance causes a small reduction of the dyes, thus a small reduction of generation rate. However, when the overlap distance is greater than 2 nm, an increase of the overlap distance causes a decrease of dyes, then a reduction of the generation rate.

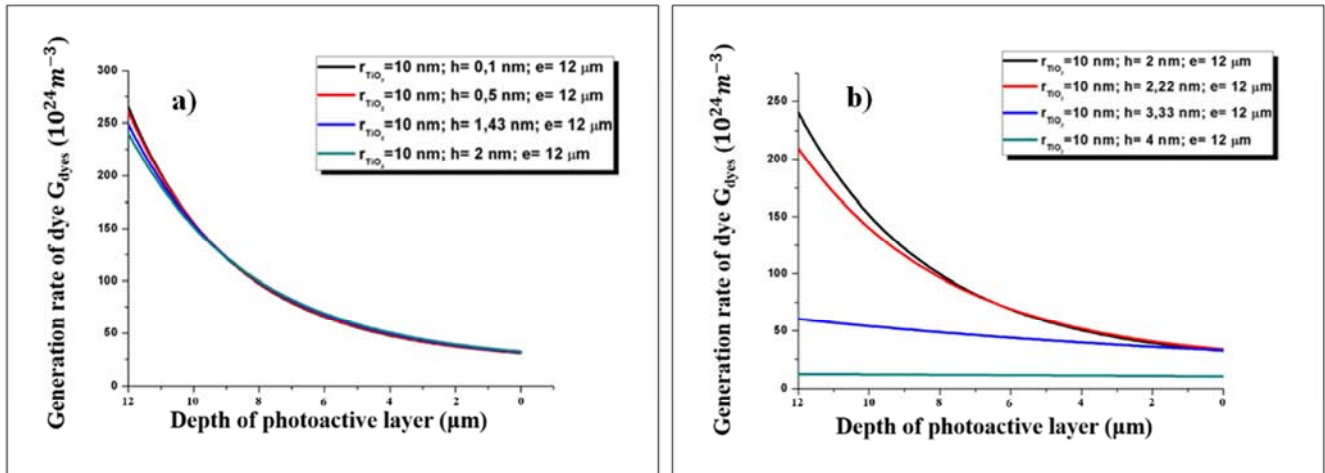


Figure 9. Generation rate depending on the depth of the cell, for different values of h .

Figure 10 presents the diffusion coefficient of electrons as a function of overlap distance between two TiO_2 nanoparticles h for a radius equal to 10 nm. When h increases, the diffusion coefficient increases. In fact, when h increases, the contact between particles increases, thus the diffusion between two particles increases. However, we notice that the curve changes when the overlap distance equals to 2 nm. In fact, the diffusion coefficient is described by two different equations as seen in the precedent section.

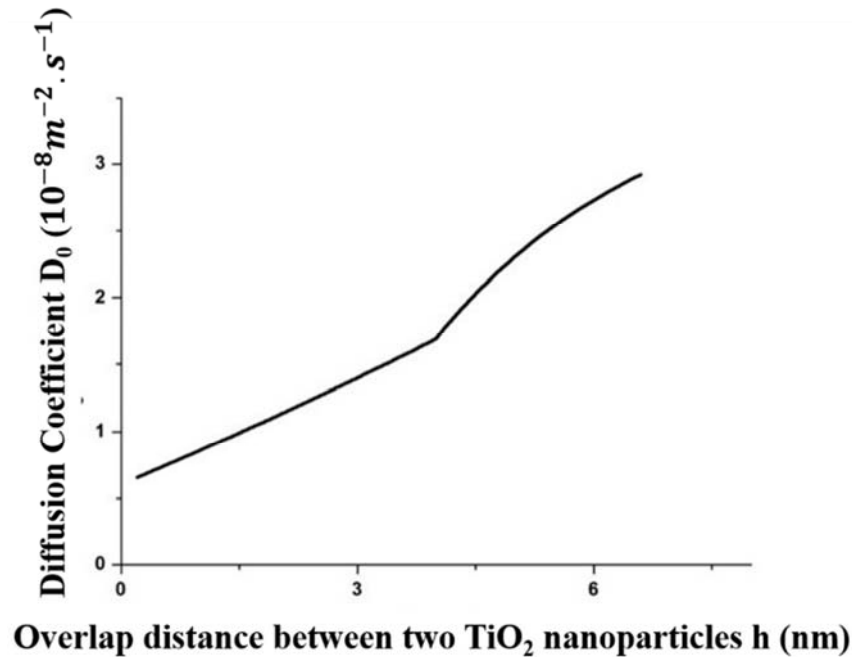


Figure 10. Diffusion coefficient as a function of overlap distance.

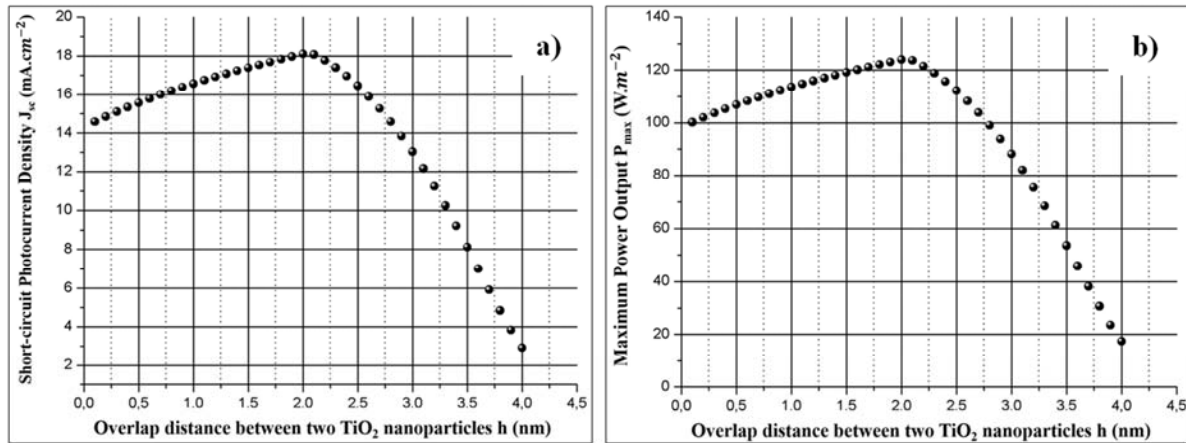


Figure 11. Short-circuit photocurrent density and Maximum power output as a function of overlap distance.

Figure 11.a represents the short-circuit current density as a function of overlap distance. We notice that when the overlap distance h increases, the short circuit current density increases for h smaller than 2 nm, but the short circuit current density decreases when h greater than 2 nm with a maximum to $h = 2$ nm. Indeed, for h smaller than 2 nm, when the overlap distance increases the generation rate is almost the same (Cf figure 9.a) but the diffusion coefficient increases (Cf figure 10). Then, the short circuit current density increases. However, when h is smaller than 2 nm, when the overlap distance increases, the generation rate decreases (Cf figure 9.b). Then, even if the diffusion coefficient increases, we assist to a reduction of photon. Thus, short circuit current density decreases.

Figure 11.b represents the maximum power output as a function of overlap distance. We see that, we have the same behavior as for figure 11.a. Then, we notice that it exists an optimal overlap distance $h = 2$ nm, for TiO_2 radius equal to 10 nm.

4. Conclusion

Our model allows us to see the influence of overlap distance between two TiO_2 particles (h) on the generation rate. Moreover, the influence of h in the electric output parameters (J_{sc} , P_{max} ...) is studied.

We see that when $h \leq 2$ nm the generation rate is nearly the same. However, when $h > 2$ nm the generation rate is reduced. Furthermore, it was found that the optimal overlap distance is 2 nm for for TiO_2 radius equal to 10 nm.

Our results agree with the ones found in the literature. However, this model has some limitation: the particles are not necessarily spherical and of the same size and the difference between the reflected coefficient diffused and collimated could be taken into account for better precision.

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